NSN 5961-01-089-7020

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-089-7020 **Inclosure Material:** Metal **Overall Length:** 0.585 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and mounting hardware **Overall Width Across Flats:** Between 0.552 inches and 0.562 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 off-state voltage, peak **Current Rating Per Characteristic:** 25.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 0.5 watts small-signal input power, common-collector nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 115.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Test Data Document:** 91417-127765 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No